TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX16373FT

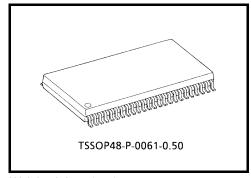
Low-Voltage 16-Bit D-Type Latch with 5-V Tolerant Inputs and Outputs

The TC74LCX16373FT is a high-performance CMOS 16-bit D-type latch. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (2.5-V or 3.3-V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 16-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}) which are common to each byte. It can be used as two 8-bit latches or one 16-bit latch. When the \overline{OE} input is high, the outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

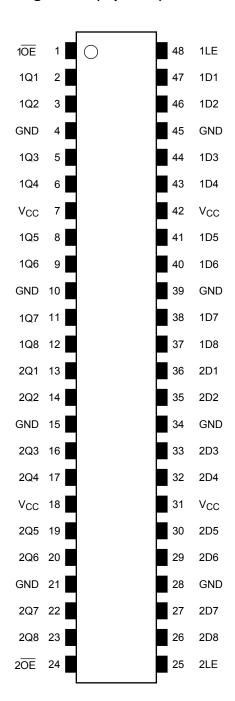


Weight: 0.25 g (typ.)

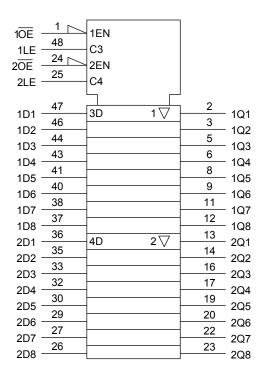
Features

- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 5.4 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- · Package: TSSOP (thin shrink small outline package)
- Power-down protection provided on all inputs and outputs

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

	Outputs		
1OE	1LE	1D1-1D8	1Q1-1Q8
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

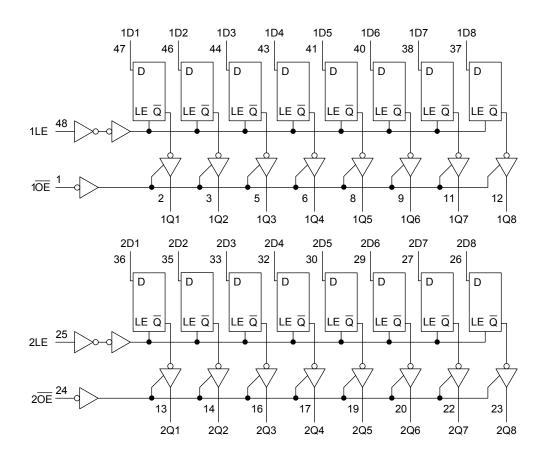
	Outputs		
2OE	2LE	2D1-2D8	2Q1-2Q8
Н	X	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5 to 6.0	V
Input voltage	V _{IN}	-0.5 to 7.0	٧
Output voltage	Vour	-0.5 to 7.0 (Note 2)	V
Output voitage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
Tower supply voltage	vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vour	0 to 5.5 (Note 3)	V	
Output voltage	V _{OUT}	0 to V _{CC} (Note 4)	V	
		±24 (Note 5)		
Output current	I _{OH} /I _{OL}	±12 (Note 6)	mA	
		±8 (Note 7)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Co	Test Condition		Min		Unit	
Ondracterist	103	Cymbol	rest condition		V _{CC} (V)	IVIIII	Max	Onic	
	H-level	V	Ver		2.3 to 2.7	1.7	1.7 —		
Input voltage	i i-level	V _{IH}		_	2.7 to 3.6	2.0		V	
iliput voltage	L-level	\/			2.3 to 2.7	_	0.7	V	
	L-ievei	V _{IL}	_	_	2.7 to 3.6	_	0.8		
				$I_{OH} = -100 \mu A$	2.3 to 3.6	V _{CC} - 0.2			
				$I_{OH} = -8 \text{ mA}$	2.3	1.8			
	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2			
				$I_{OH} = -18 \text{ n}$	$I_{OH} = -18 \text{ mA}$	3.0	2.4		
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2		V	
			$I_{OL} = 100 \mu A$	$I_{OL} = 100 \ \mu A$	2.3 to 3.6	_	0.2		
					$I_{OL} = 8 \text{ mA}$	2.3	_	0.6	
	L-level	V _{OL}			$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
				$I_{OL} = 16 \text{ mA}$	3.0	_	0.4		
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55		
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.3 to 3.6	_	±5.0	μΑ	
3 state output OEE sta	tate output OFF state current		$V_{IN} = V_{IH}$ or V_{IL}	2.3 to 3.6	_	±5.0	μА		
3-State output OFF State current		loz	V _{OUT} = 0 to 5.5 V		2.3 to 3.0		±3.0	μΑ	
Power-off leakage curi	rent	loff	$V_{IN}/V_{OUT} = 5.5 \text{ V}$		0	_	10.0	μΑ	
Quiescent supply curre	Quiescent supply current		$V_{IN} = V_{CC}$ or GND		2.3 to 3.6		20.0		
Quioscont supply cult			$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 ^{\circ}$	V	2.3 to 3.6	_	±20.0	μА	
Increase in Icc per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.3 to 3.6	_	500		



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	ymbol Test Condition				Max	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	CL(pF)	Min	IVIAX	Offic
Dropogation delay time	.		2.5 ± 0.2	30	1.5	6.5	
Propagation delay time (D-Q)	t _{pLH}	Figure 1, Figure 2	2.7	50	1.5	5.9	ns
(D-Q)	t _{pHL}		3.3 ± 0.3	50	1.5	5.4	
Desperation delevitime	_		2.5 ± 0.2	30	1.5	6.6	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	50	1.5	6.4	ns
(LE-Q)	t _{pHL}		3.3 ± 0.3	50	1.5	5.5	
			2.5 ± 0.2	30	1.5	7.9	
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.7	50	1.5	6.5	ns
	t _{pZH}		3.3 ± 0.3	50	1.5	6.1	
		Figure 1, Figure 3	2.5 ± 0.2	30	1.5	7.2	ns
3-state output disable time	t _{pLZ}		2.7	50	1.5	6.3	
	t _{pHZ}		3.3 ± 0.3	50	1.5	6.0	
NATIONAL CONTRACTOR AND ADMINISTRACTOR ADMINISTRACTOR AND ADMINISTRACTOR AND ADMINISTRACTOR AD			2.5 ± 0.2	30	3.5	_	
Minimum pulse width	t _w (H)	Figure 1, Figure 2	2.7	50	3.0	_	ns
(LE)			3.3 ± 0.3	50	3.0	_	
			2.5 ± 0.2	30	3.0	_	
Minimum setup time	ts	Figure 1, Figure 2	2.7	50	2.5	_	ns
			3.3 ± 0.3	50	2.5	_	
			2.5 ± 0.2	30	2.0	_	
Minimum hold time	t _h	Figure 1, Figure 2	2.7	50	1.5	_	ns
			3.3 ± 0.3	50	1.5	_	
			2.5 ± 0.2	30	_	_	
Output to output skew	t _{osLH}	(Note)	2.7	50	_	_	ns
	t _{osHL}		3.3 ± 0.3	50	_	1.0	

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V, C _L =30pF	2.5	0.6	V
dynamic V _{OL}	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}, C_L = 50 \text{pF}$	3.3	0.8	V
Quiet output minimum	V _{OL} V	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}, C_L = 30 \text{pF}$	2.5	0.6	V
dynamic V _{OL}	IVOLVI	V _{IH} = 3.3 V, V _{IL} = 0 V, C _L =50pF	3.3	8.0	V



Capacitive Characteristics (Ta = 25°C)

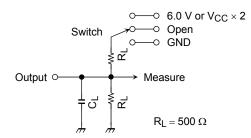
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (No	e) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		
t _{pHZ} , t _{pZH}	GND		

Figure 1

AC Waveform

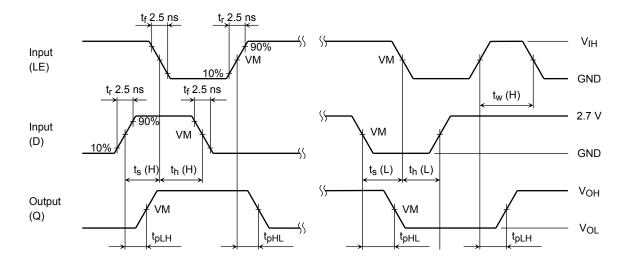


Figure 2 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

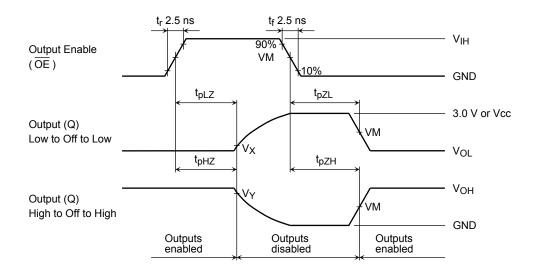


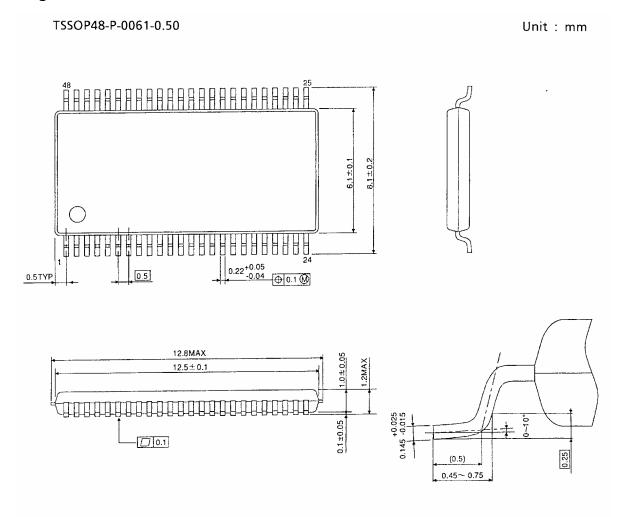
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol	V _{CC}					
Symbol	$3.3\pm0.3~\textrm{V}$	2.7 V	$2.5\pm0.2\;\textrm{V}$			
V_{IH}	2.7 V	2.7 V	V _{CC}			
V _M	1.5 V	1.5 V	V _{CC} /2			
VX	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V			
VY	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 0.15 V			

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Package Dimensions



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Weight: 0.25 g (typ.)

Note: Lead (Pb)-Free Packages

TSSOP48-P-0061-0.50

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